

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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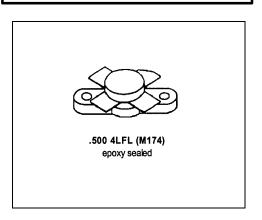
PHONE: (215) 631-9840 FAX: (215) 631-9855

MS1007

RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

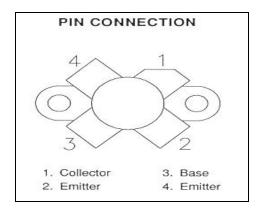
Features

- 30 MHz
- 50 VOLTS
- P_{OUT} = 150 WATTS
- $G_P = 14 \text{ dB MINIMUM}$
- COMMON EMITTER CONFIGURATION



DESCRIPTION:

The MS1007 is a 50V epitaxial silicon NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions.



ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

| Symbol | Parameter | Value | Unit | |
|-------------------|---------------------------|-------------|------|--|
| V _{CBO} | Collector-Base Voltage | 110 | V | |
| V _{CEO} | Collector-Emitter Voltage | 55 | V | |
| V _{EBO} | Emitter-Base Voltage | 4.0 | V | |
| Ic | Device Current | 10 | Α | |
| P _{DISS} | Power Dissipation | 233 | W | |
| Τ _J | Junction Temperature | +200 | °C | |
| T _{STG} | Storage Temperature | -65 to +150 | °C | |

Thermal Data

| R _{TH(J-C)} | Thermal Resistance Junction-case | 0.75 | °C/W |
|----------------------|----------------------------------|------|------|
|----------------------|----------------------------------|------|------|



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ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

| Symbol | Test Conditions | | Value | | | Unit | |
|-------------------|------------------------|-----------------------|-------|------|------|-------|----|
| | | Mi | n. | Typ. | Max. | Offic | |
| BV _{CBO} | I _C = 100mA | I _E = 0mA | 11 | 0 | | | V |
| BV _{CES} | I _C = 100mA | $V_{BE} = 0V$ | 11 | 0 | | | V |
| BV _{CEO} | I _C = 100mA | $I_B = 0mA$ | 5: | 5 | | | V |
| BV _{EBO} | I _E = 10mA | $I_C = 0mA$ | 4. | 0 | | | V |
| I _{CEO} | V _{CE} = 30V | I _E = 0 mA | | - | | 5 | mA |
| I _{CES} | V _{CE} = 60V | I _E = 0mA | | - | | 5 | mA |
| h _{FE} | $V_{CE} = 6V$ | $I_C = 1.4A$ | 18 | 3 | | 43.5 | |

DYNAMIC

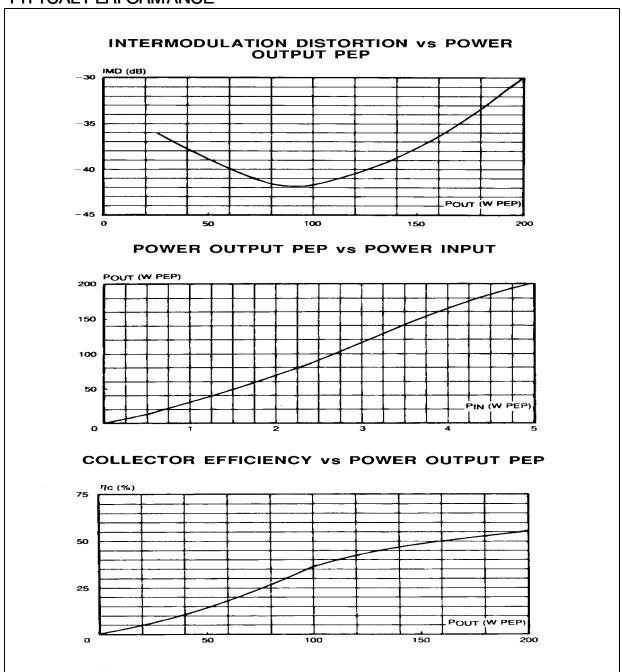
| Symbol | Test Conditions | | | Value | | | |
|--------------------|----------------------------|------------------------|-------------------------|-------|------|------|------|
| | | | Min. | Тур. | Max. | Unit | |
| \mathbf{P}_{OUT} | f = 30 MHz | $V_{CE} = 50V$ | I _{CQ} = 100mA | 150 | | | WPEP |
| G₽ | P _{OUT} = 150WPEP | V _{CE} = 50V | I _{CQ} = 100mA | 14 | | | dB |
| IMD | P _{OUT} = 150WPEP | V _{CE} = 50V | I _{CQ} = 100mA | | | -30 | dBc |
| ης | P _{OUT} = 150WPEP | $V_{CE} = 50V$ | I _{CQ} = 100mA | 37 | | | % |
| Сов | f = 1 MHz | V _{CB} = 50 V | | | | 220 | pf |
| Conditions | f1 = 30.000MHz | f2 = 30.001M | Hz | | | | |



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TYPICAL PERFORMANCE





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PACKAGE MECHANICAL DATA

